



MT06N020AL

主要参数 MAIN CHARACTERISTICS

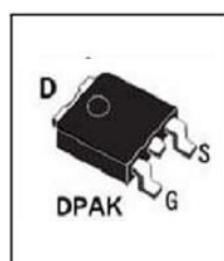
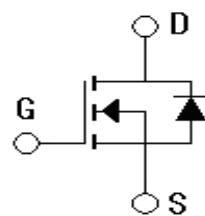
ID	50A
V _{DSS}	60V
R _{dson-max} (@V _{gs} =10V)	17mΩ
Q _{g-typ}	47.4nC

用途

- 高功率 DC/DC 转换与功率开关
- 直流电机控制
- 不间断电源
- High power DC/DC converters and switch mode power supplies
- DC motor control
- Uninterruptible power supply

APPLICATIONS

封装 Package



产品特性

- 低栅极电荷
- 低 R_{dson}
- 开关速度快
- 产品全部经过雪崩测试
- 高抗 dv/dt 能力
- RoHS 产品
- Low gate charge
- Low R_{dson}
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- RoHS product

FEATURES

订货信息 ORDER MESSAGE

订货型号 Order codes				印 记 Marking	封 装 Package
有卤-条管 Halogen-Tube	无卤-条管 Halogen-Free-Tube	有卤-编带 Halogen-Reel	无卤-编带 Halogen-Free-Reel		
MT06N020AL-R-B	MT06N020AL-R-BR	MT06N020AL-R-A	MT06N020AL-R-AR	MT06N020AL	DPAK



MT06N020AL

绝对最大额定值 ABSOLUTE RATINGS (T_c=25°C)

项目 Parameter	符号 Symbol	数值 Value	单位 Unit
		MT06N020AL	
最高漏极—源极直流电压 Drain-Source Voltage	V _{DSS}	60	V
连续漏极电流 Drain Current -continuous	I _D T=25°C	50*	A
	I _D T=100°C	35*	A
最大脉冲漏极电流 (注 1) Drain Current - pulse (note 1)	I _{DM}	200*	A
最高栅源电压 Gate-Source Voltage	V _{GSS}	±20	V
单脉冲雪崩能量 (注 2) Single Pulsed Avalanche Energy (note 2)	E _{AS}	196	mJ
雪崩电流 Avalanche Current	I _{AS}	28	A
耗散功率 Power Dissipation	P _D T _c =25°C	69.4	W
	-Derate above 25°C	0.55	W/°C
最高结温及存储温度 Operating and Storage Temperature Range	T _J , T _{STG}	-55~+150	°C
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	T _L	300	°C

*漏极电流由最高结温限制

*Drain current limited by maximum junction temperature



MT06N020AL

电特性 ELECTRICAL CHARACTERISTICS

项 目 Parameter	符 号 Symbol	测试条件 Tests conditions	最 小 Min	典 型 Typ	最 大 Max	单 位 Units
关态特性 Off -Characteristics						
漏—源击穿电压 Drain-Source Voltage	BV_{DSS}	$I_D=250\mu A, V_{GS}=0V$	60	-	-	V
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V, T_C=25^\circ C$	-	-	1	μA
		$V_{DS}=48V, V_{GS}=0V, T_C=100^\circ C$	-	-	10	μA
正向栅极体漏电流 Gate-body leakage current, forward	I_{GSSF}	$V_{DS}=0V, V_{GS}=20V$	-	-	100	nA
反向栅极体漏电流 Gate-body leakage current, reverse	I_{GSSR}	$V_{DS}=0V, V_{GS}=-20V$	-	-	-100	nA
通态特性 On-Characteristics						
阈值电压 Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D=250\mu A$	1.0	-	2.5	V
静态导通电阻 Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=4.5V, I_D=6A$	-	16.5	21.0	$m\Omega$
	$R_{DS(ON)}$	$V_{GS}=10V, I_D=10A$	-	12.5	17.0	$m\Omega$
动态特性 Dynamic Characteristics						
输入电容 Input capacitance	C_{iss}	$V_{DS}=30V, V_{GS}=0V, f=1.0MHz$	-	1863	-	pF
输出电容 Output capacitance	C_{oss}		-	182	-	pF
反向传输电容 Reverse transfer capacitance	C_{rss}		-	125	-	pF



电特性 ELECTRICAL CHARACTERISTICS

开关特性 Switching Characteristics							
延迟时间 Turn-On delay time	t _{d(on)}	V _{DD} =30V, I _D =30A, R _G =3.0Ω (note 3, 4)	-	15.4	-	ns	
上升时间 Turn-On rise time	t _r		-	76.6	-	ns	
延迟时间 Turn-Off delay time	t _{d(off)}		-	60.6	-	ns	
下降时间 Turn-Off Fall time	t _f		-	97.6	-	ns	
栅极电荷总量 Total Gate Charge	Q _g	V _{DS} =30V , I _D =30A V _{GS} =10V (note 3, 4)	-	47.4	-	nC	
栅一源电荷 Gate-Source charge	Q _{gs}		-	8.1	-	nC	
栅一漏电荷 Gate-Drain charge	Q _{gd}		-	12.3	-	nC	
漏一源二极管特性及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings							
正向最大连续电流							
Maximum Continuous Drain -Source Diode Forward Current		I _S	-	-	50	A	
正向最大脉冲电流							
Maximum Pulsed Drain-Source Diode Forward Current		I _{SM}	-	-	200	A	
正向压降							
Drain-Source Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =10A	-	-	1.2	V	
反向恢复时间	t _{rr}	V _{GS} =0V, I _S =30A dI _F /dt=100A/μs (note 3)	-	38.5	-	ns	
反向恢复电荷	Q _{rr}		-	33.8	-	nC	
Reverse recovery charge							

热特性 THERMAL CHARACTERISTIC

项 目 Parameter	符 号 Symbol	最大 Max		单 位 Unit
		MT06N020AL		
结到管壳的热阻 Thermal Resistance, Junction to Case	R _{th(j-c)}	1.8		°C/W
结到环境的热阻 Thermal Resistance, Junction to Ambient	R _{th(j-A)}	100		°C/W

注释:

- 1: 脉冲宽度由最高结温限制
 2: L=0.5mH, V_{DD}=50V, R_G=25 Ω, 起始结温
 T_J=25°C
 3: 脉冲测试: 脉冲宽度≤300μs, 占空比≤2%
 4: 基本与工作温度无关

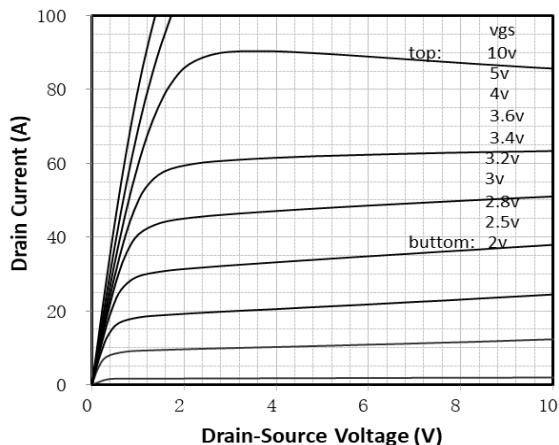
Notes:

- 1: Pulse width limited by maximum junction temperature
 2: L=0.5mH, V_{DD}=50V, R_G=25 Ω, Starting T_J=25°C
 3: Pulse Test: Pulse Width ≤300μs, Duty Cycle≤2%
 4: Essentially independent of operating temperature

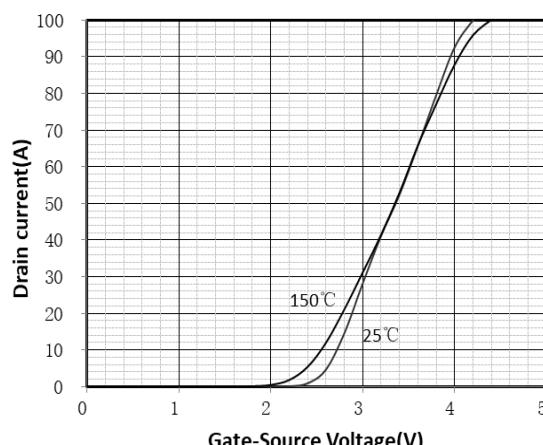


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

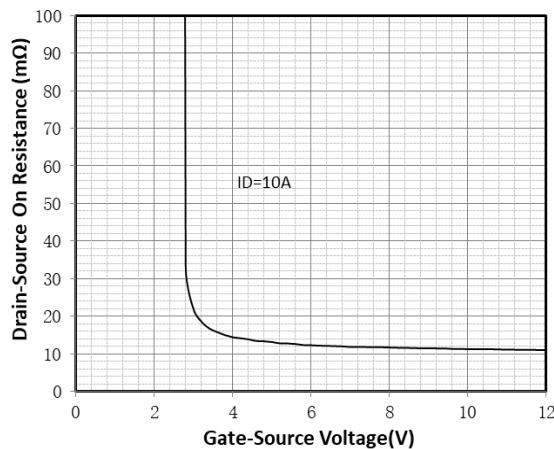
On-Region Characteristics



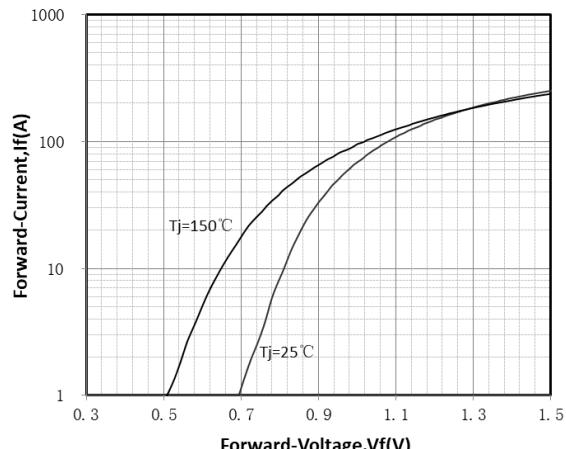
Transfer Characteristics



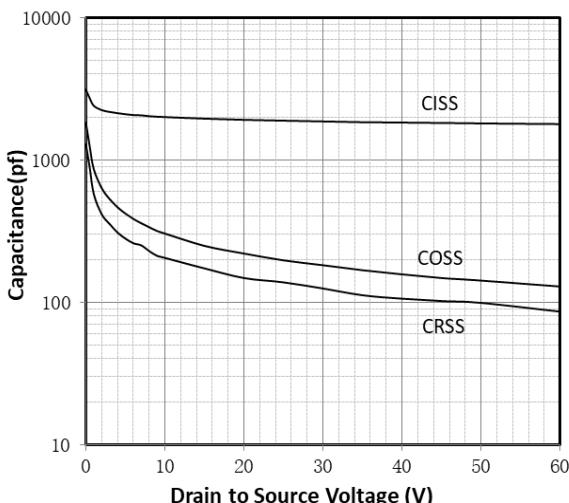
On-Resistance Variation vs. Drain Current and Gate Voltage



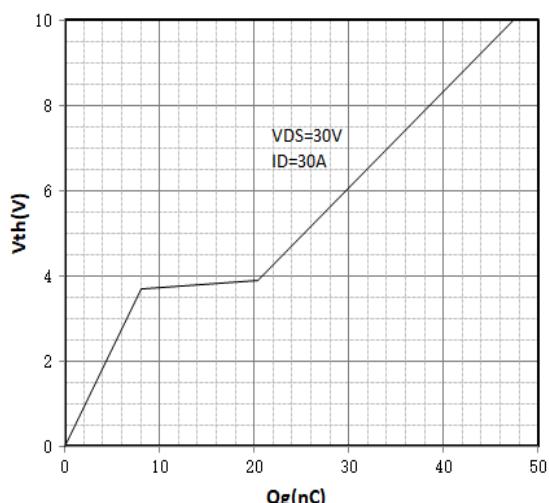
Body Diode Forward Voltage Variation vs. Source Current and Temperature



Capacitance Characteristics

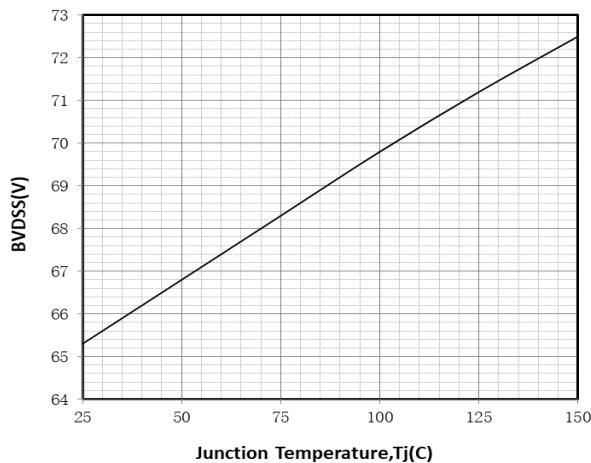


Gate Charge Characteristics

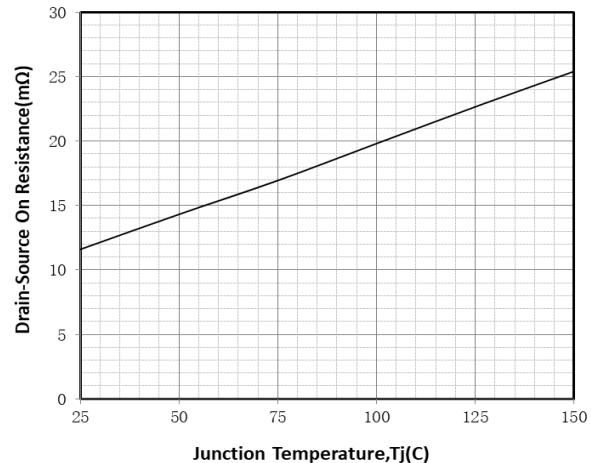


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

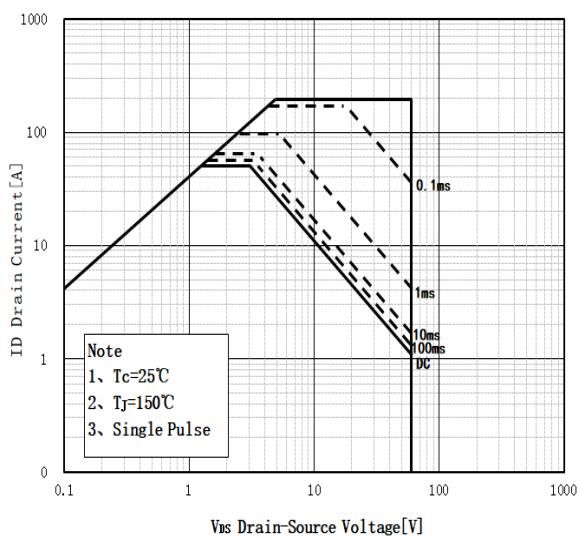
Breakdown Voltage Variation vs. Temperature



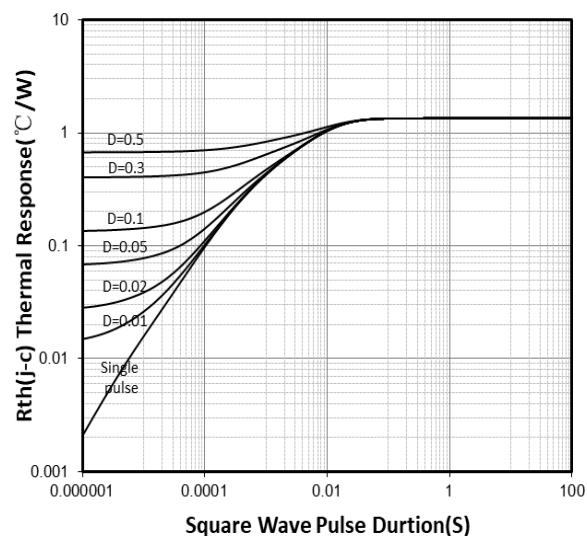
On-Resistance Variation vs. Temperature



Maximum Safe Operating Area



Transient Thermal Response Curve



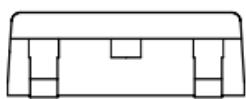
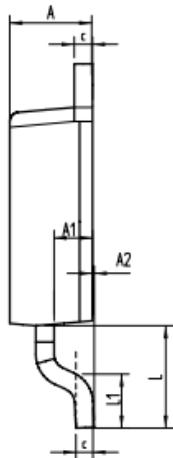
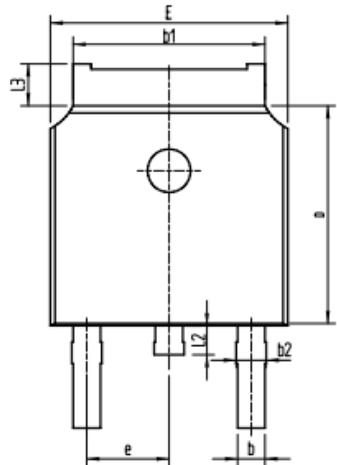


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外形尺寸 PACKAGE MECHANICAL DATA

DPAK

单位 Unit: mm



SYMBOL	mm	
	MIN	MAX
A	2.16	2.41
A1	0.97	1.17
A2	0.00	0.15
b	0.63	0.93
b1	5.13	5.53
b2	0.66	0.96
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
e	2.286BSC	
L	2.50	3.30
L1	1.20	1.80
L2	0.60	1.00
L3	0.85	1.30



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